

FJP3305 High Voltage Fast-Switching NPN Power Transistor

- · High Voltage Capability
- · High Switching Speed
- · Suitable for Electronic Ballast and Switching Regulator



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current (DC)	4	Α
I _{CP}	Collector Current (Pulse)	8	Α
I _B	Base Current	2	Α
P _C	Collector Dissipation (T _C = 25°C)	75	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
BV _{CBO}	Collector-Base Breakdwon Voltage	$I_C = 500 \mu A, I_E = 0$	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5mA, I_B = 0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 500 \mu A, I_C = 0$	9			V
I _{CBO}	Collector Cut-off Current	V _{CB} = 700V, I _E = 0			1	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} = 9V, I _C = 0			1	μΑ
h _{FE1}	DC Current Gain *	V _{CE} = 5V, I _C = 1A V _{CE} = 5V, I _C = 2A	19 8		35 40	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$ $I_C = 2A, I_B = 0.5A$ $I_C = 4A, I_B = 1A$			0.5 0.6 1.0	V V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 1A, I _B = 0.2A I _C = 2A, I _B = 0.5A			1.2 1.6	V V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MHz
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 1MHz		65		pF
t _{ON}	Turn On Time	V _{CC} = 125V, I _C = 2A			0.8	μs
t _{STG}	Storge Time	$I_{B1} = -I_{B2} = 0.4A$ - $R_1 = 62.5\Omega$			4.0	μs
t _F	Fall Time	11[- 02.052			0.9	μs

^{*} Pulse Test: PW \leq 300 μ s, Duty Cycle \leq 2%

h_{FE} Classification

Classification	H1	H2
h _{FE1}	19 ~ 28	26 ~ 35

Typical Performance Characteristics

Figure 1. Static Characteristic

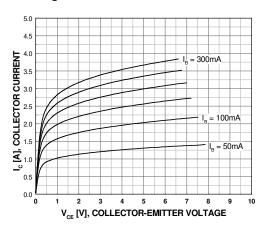


Figure 3. DC Current Gain (O-Grade)

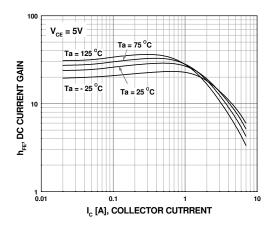


Figure 5. Saturatin Voltage (O-Grade)

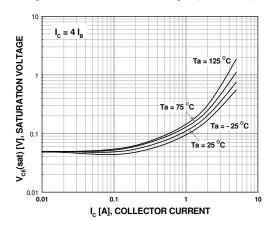


Figure 2. DC Current Gain (R-Grade)

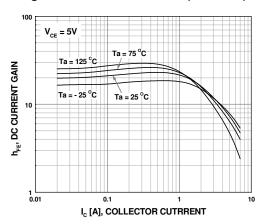


Figure 4. Saturation Voltage (R-Grade)

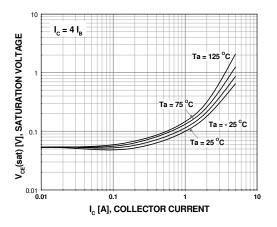
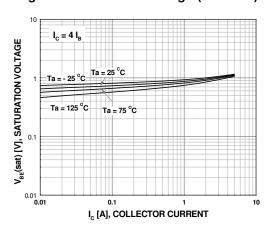


Figure 6. Saturation Voltage (R-Grade)



Typical Performance Characteristics (Continued)

Figure 7. Saturation Voltage (O-Grade)

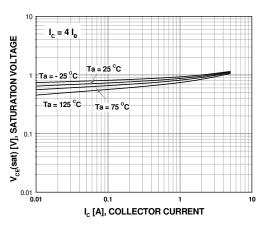


Figure 8. Switching Time

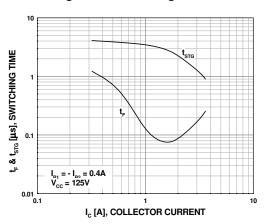


Figure 9. Reverse Biased Safe Operating Area

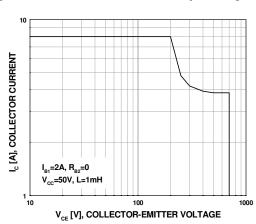


Figure 10. Forward Biased Safe Operating Area

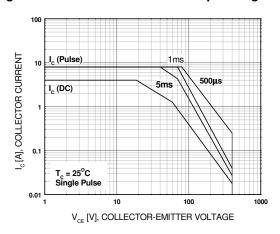
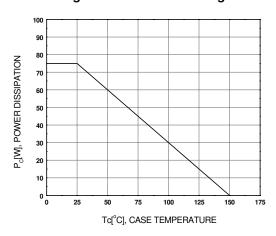
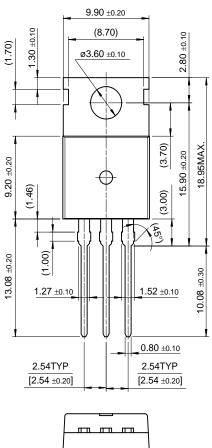


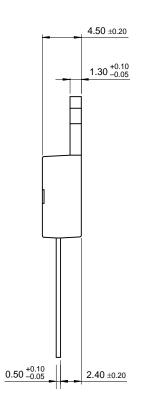
Figure 11. Power Derating



Mechanical Dimensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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Datasheet Identification	Product Status	Definition
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FJP3305

NPN Silicon Transistor

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- High Speed Switching
- Suitable for Electronic Ballast and Switching Regulator

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Product status/pricing/packaging

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Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
FJP3305	Full Production	Full Production	\$0.418	<u>TO-220</u>	3		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> &3 <u>Line 3:</u> J3305
FJP3305H1TU	Full Production	Full Production	\$0.418	<u>TO-220</u>	3		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> &3 <u>Line 3:</u> J3305-1
FJP3305H2TU	Full Production	Full Production	\$0.418	<u>TO-220</u>	3		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> &3 <u>Line 3:</u> J3305-2
FJP3305TU	Full Production		\$0.426	<u>TO-220</u>	3	RAIL	Line 1: \$Y (Fairchild logo)

	<u>e 3:</u> J3305
Full Production	

^{*} Fairchild 1,000 piece Budgetary Pricing

** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product FJP3305 is available. Click here for more information .

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Models

Package & leads Condition Temperature range		Vcc range	Software version	Revision date	
PSPICE					
TO-220-3 <u>Electrical</u> -65°C to 150°C		0V to 8V	OrCAD 10.3	May 11, 2007	

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Qualification Support

Click on a product for detailed qualification data

Product
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